

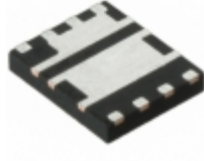

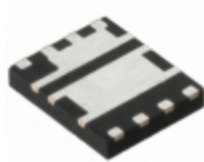
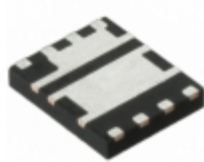



	<h2>FDMS3600S</h2>
	<p>codice articolo del costruttore: FDMS3600S</p> <hr/> <p>Costruttore / Marca: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Parte della descrizione: MOSFET 2N-CH 25V 15A/30A 8-PQFN</p> <hr/> <p>Specifiche: FDMS3600S.pdf</p> <hr/> <p>Stato di RoHS: Senza piombo / RoHS conforme</p> <hr/> <p>Condizione di scorta: New original, 5302 pcs Stock Available.</p> <hr/> <p>Nave da: Hong Kong</p> <hr/> <p>Modo di spedizione: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

specificazioni

Modello di prodotti	FDMS3600S
fabbricante	AMI Semiconductor / ON Semiconductor
Descrizione	MOSFET 2N-CH 25V 15A/30A 8-PQFN
Categoria	Prodotti a semiconduttore discreti > Transistor-FET,
Stato parte	5302 pcs Stock
Vgs (th) (max) a Id	2.7V @ 250µA
Contenitore dispositivo fornitore	Power56
Serie	PowerTrench®
Rds On (max) a Id, Vgs	5.6 mOhm @ 15A, 10V
Potenza - Max	1W
imballaggio	Tape & Reel (TR)
Contenitore / involucri	8-PowerTDFN
Altri nomi	FDMS3600S-ND
temperatura di esercizio	-55°C ~ 150°C (TJ)
Tipo montaggio	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Produttore tempi di consegna standard	39 Weeks
Stato senza piombo / Stato RoHS	Lead free / RoHS Compliant
Capacità di ingresso (Ciss) (Max) @ Vds	1680pF @ 13V
Carica Gate (Qg) (Max) @ Vgs	27nC @ 10V
Tipo FET	2 N-Channel (Dual) Asymmetrical
Caratteristica FET	Logic Level Gate
Tensione drain-source (Vdss)	25V
Descrizione dettagliata	Mosfet Array 2 N-Channel (Dual) Asymmetrical 25V 15A,
Corrente - Drain continuo (Id) @ 25 ° C	15A, 30A
Numero di parte base	FDMS3600S

Potresti essere anche interessato:

 <p>FDMS3600AS MOS FAIRCHILD FAIRCHILD QFN</p>	 <p>FDMS3572 MOS FAIRCHILD FAIRCHILD QFN</p>	 <p>FDMS3602S Fairchild/ON Semiconductor MOSFET 2N-CH 25V 15A/26A POWER56</p>	 <p>FDMS3600AS Fairchild/ON Semiconductor MOSFET 2N-CH 25V 15A/30A 8-PQFN</p>
 <p>FDMS3600AS AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 25V 15A/30A 8-PQFN</p>	 <p>FDMS3602S AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 25V 15A/26A POWER56</p>	 <p>FDMS3602S MOS FAIRCHILD FAIRCHILD SON8</p>	 <p>FDMS3602AS AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 25V 15A/26A POWER56</p>

FDMS3600S Parola chiave correlata

Di Più

FDMS3600S AMI Semiconductor / ON Semiconductor	Scheda tecnica FDMS3600S	Schede tecniche FDMS3600S	FDMS3600S PDF	AMI Semiconductor / ON Semiconductor FDMS3600S
FDMS3600S elettronico	Componenti FDMS3600S	Distributore FDMS3600S	Immagine FDMS3600S	FDMS3600S Part
FDMS3600S Prezzo	FDMS3600S Produttore	Immagine FDMS3600S	Stock FDMS3600S	Inventario FDMS3600S
FDMS3600S Nuovo	FDMS3600S Originale	FDMS3600S garantito	FDMS3600S RFQ	FDMS3600S Ordina online

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